

GaN layer laterally overgrown on the main surface which is 0.2° off-angled from
C-plane of sapphire substrate

FIG. B1 optical microscope image (magnification 50x)

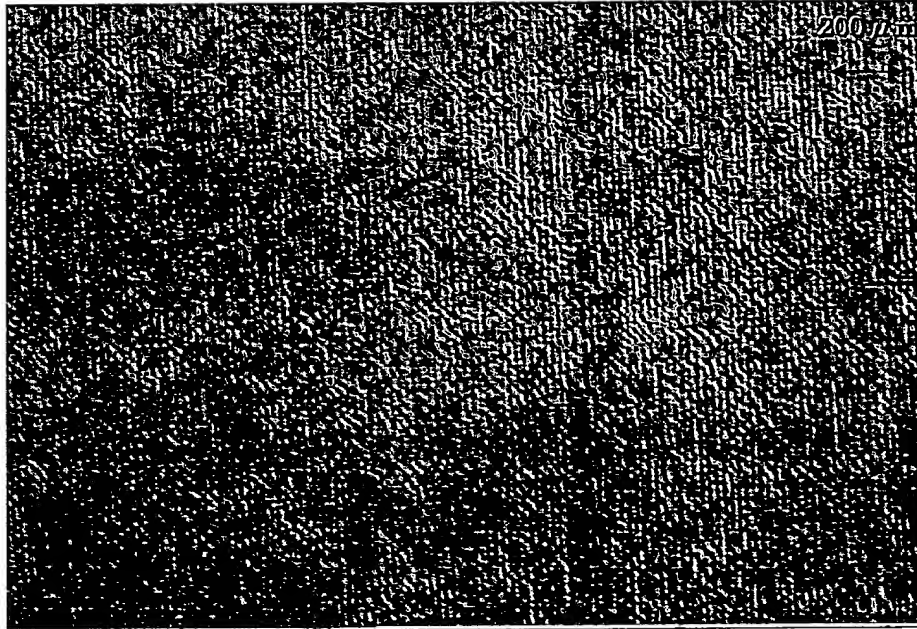
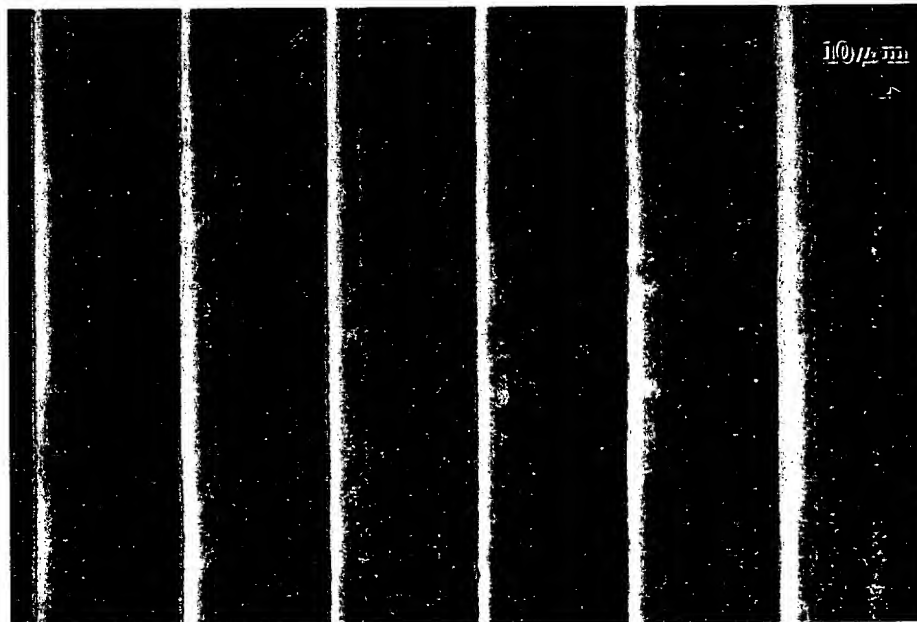


FIG. B2 fluorescence microscope image (magnification 1,000x)





EXPERIMENTAL REPORT

GaN layer laterally overgrown on C-plane of sapphire substrate

FIG. A1 optical microscope image (magnification 50x)

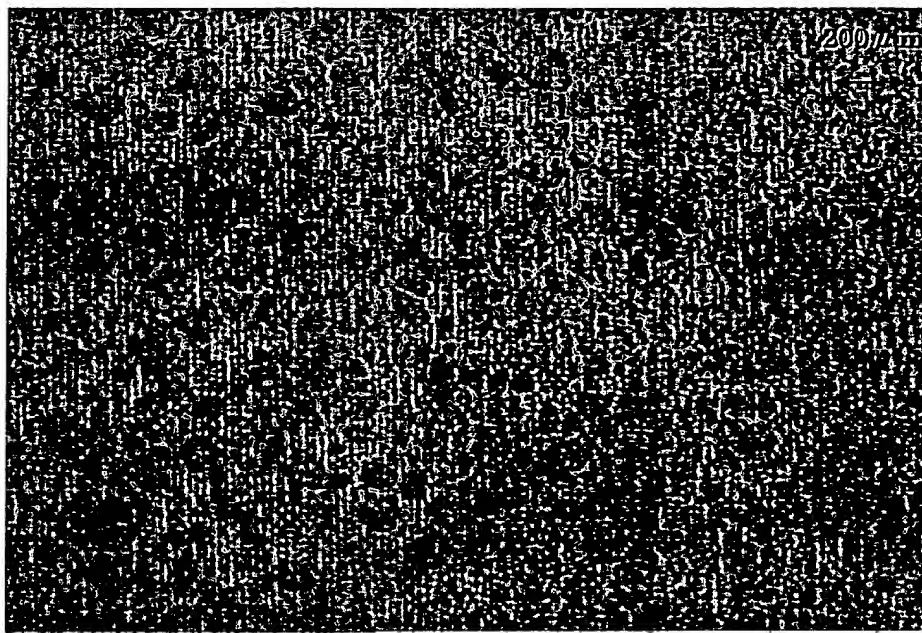


FIG. A2 fluorescence microscope image (magnification 1,000x)

